

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

TLP3061(S),TLP3062(S),TLP3063(S)

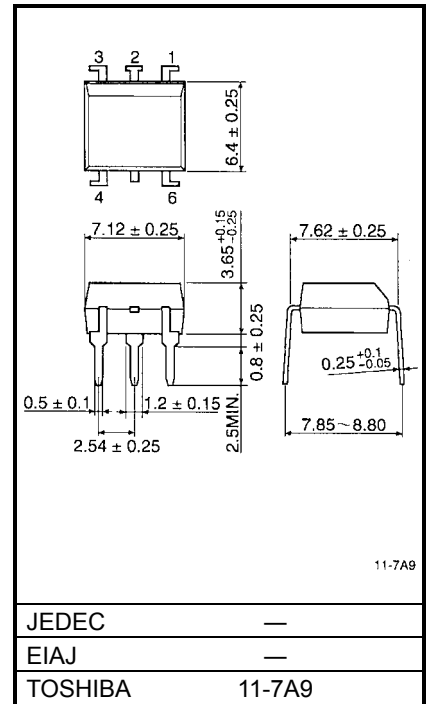
Unit: mm

OFFICE MACHINE
HOUSEHOLD USE EQUIPMENT
TRIAC DRIVER
SOLID STATE RELAY

The TOSHIBA TLP3061 (S), TLP3062 (S), TLP3063 (S) consist of a zero voltage crossing turn-on photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

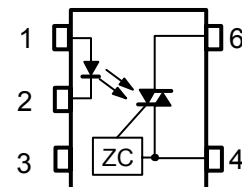
- Peak Off-State Voltage : 600 V (min)
- Trigger LED Current : 15 mA (max) (TLP3061(S))
10 mA (max) (TLP3062(S))
5 mA (max) (TLP3063(S))
- On-State Current : 100 mA (max)
- Isolation Voltage : 5000 Vrms (min)
- UL Recognized : UL1577, File No. E67349
- SEMKO Approved : SS EN60065
SS EN60950, File No.9841113
- BSI Approved : BS EN60065, File No.8385
BS EN60950, File No.8386
- Option (D4) type
VDE approved: DIN EN60747-5-2
Approved No. 40009302
Maximum operating insulation voltage: 890V_{PK}
Highest permissible over voltage: 8000V_{PK}
(Note):When a EN60747-5-2 approved type is needed,
please designate the "Option (D4)"

	Construction mechanical rating	
	7.62 mm pich Standard Type	10.16 mm pich TLPxxxxF type
Creepage Distance	7.0 mm (Min)	8.0 mm (Min)
Clearance	7.0 mm (Min)	8.0 mm (Min)
Insulation Thickness	0.5 mm (Min)	0.5 mm (Min)



weight: 0.39g

Pin Configuration (top view)



- 1: Anode
- 2: Cathode
- 3: N.C.
- 4: Terminal 1
- 6: Terminal 2

ZC:Zero-cross Circuit

Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Forward current derating (Ta ≥ 53°C)	$\Delta I_F / ^\circ\text{C}$	-0.7	mA / °C
	Peak forward current (100 μs pulse, 100 pps)	I_{FP}	1	A
	Power dissipation	P_D	100	mW
	Power dissipation derating (Ta ≥ 25°C)	$\Delta P_D / ^\circ\text{C}$	-1.0	mW / °C
	Reverse voltage	V_R	5	V
	Junction temperature	T_j	125	°C
Detector	Off-state output terminal voltage	V_{DRM}	600	V
	On-state RMS current	Ta = 25°C	100	mA
		Ta = 70°C	50	
	On-state current derating (Ta ≥ 25°C)	$\Delta I_T / ^\circ\text{C}$	-1.1	mA / °C
	Peak on-state current (100 μs pulse, 120 pps)	I_{TP}	2	A
	Peak nonrepetitive surge current (Pw = 10 ms, DC = 10%)	I_{TSM}	1.2	A
	Power dissipation	P_D	300	mW
	Power dissipation derating (Ta ≥ 25°C)	$\Delta P_D / ^\circ\text{C}$	-4.0	mW / °C
Junction temperature	T_j	115	°C	
Storage temperature range	T_{stg}	-55~150	°C	
Operating temperature range	T_{opr}	-40~100	°C	
Lead soldering temperature (10 s)	T_{sol}	260	°C	
Total package power dissipation	P_T	330	mW	
Total package power dissipation derating (Ta ≥ 25°C)	$\Delta P_T / ^\circ\text{C}$	-4.4	mW / °C	
Isolation voltage (AC, 1 min., R.H. ≤ 60%)	BV_S	5000	Vrms	

(Note 1) Device considered a two terminal device: Pins 1, 2 and 3 shorted together and pins 4 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V_{AC}	—	—	240	Vac
Forward current	I_F^*	15	20	25	mA
Peak on-state current	I_{TP}	—	—	1	A
Operating temperature	T_{opr}	-25	—	85	°C

※ In the case of TLP3062

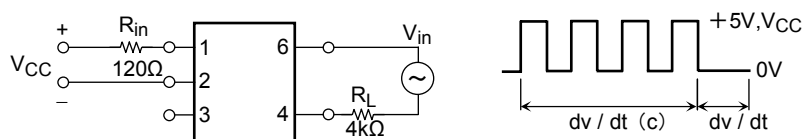
Individual Electrical Characteristics (Ta = 25°C)

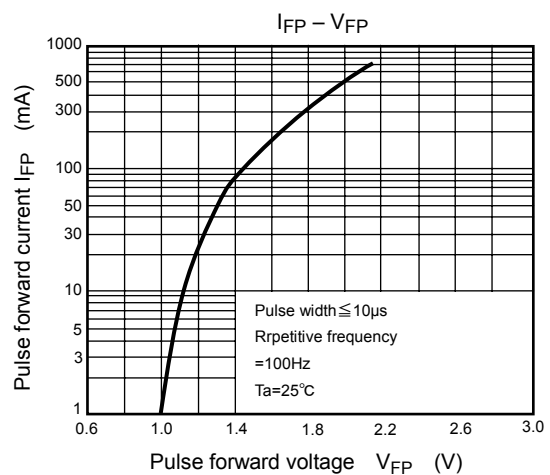
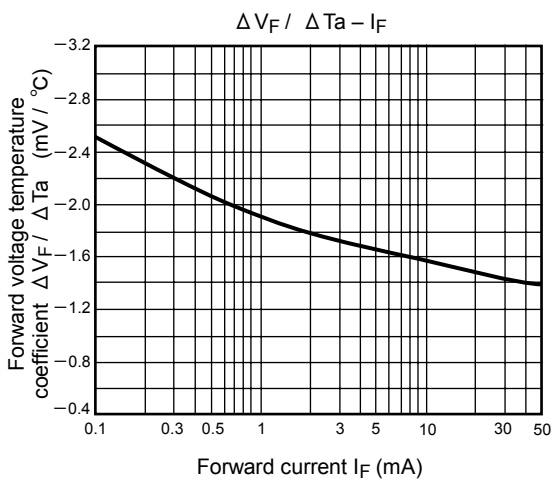
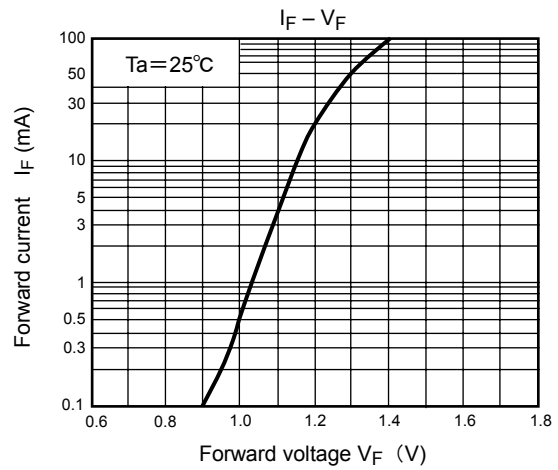
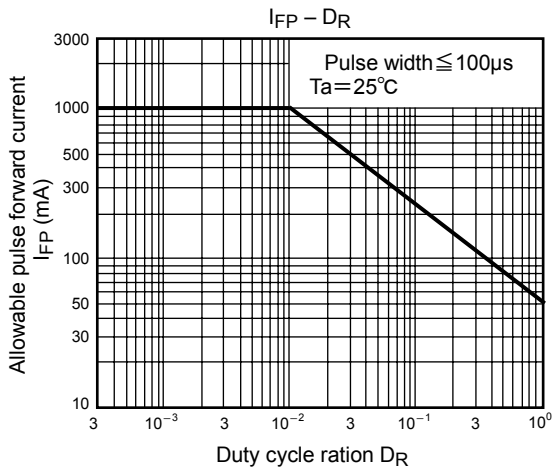
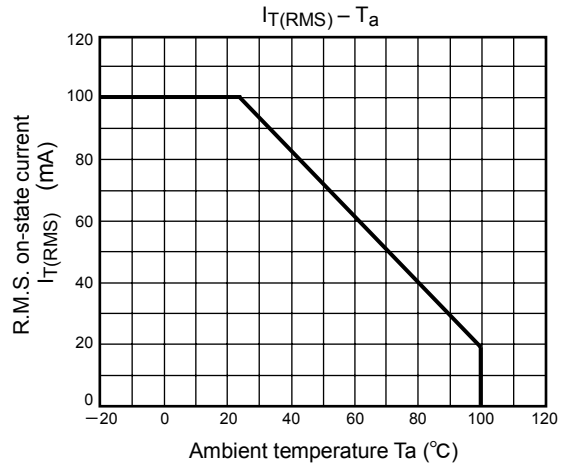
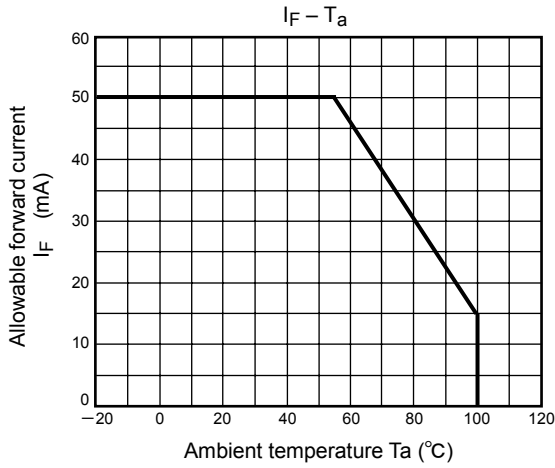
Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	10	—	pF
Detector	Peak off-state current	I_{DRM}	$V_{DRM} = 600 \text{ V}$	—	10	1000	nA
	Peak on-state voltage	V_{TM}	$I_{TM} = 100 \text{ mA}$	—	1.7	3.0	V
	Holding current	I_H	—	—	0.6	—	mA
	Critical rate of rise of off-state voltage	dv/dt	$V_{in} = 240 \text{ Vrms}, T_a = 85^\circ\text{C}$ (Fig.1)	200	500	—	V / μs
	Critical rate of rise of commutating voltage	$dv/dt (c)$	$V_{in} = 60 \text{ Vrms}, I_T = 15\text{mA}$ (Fig.1)	—	0.2	—	V / μs

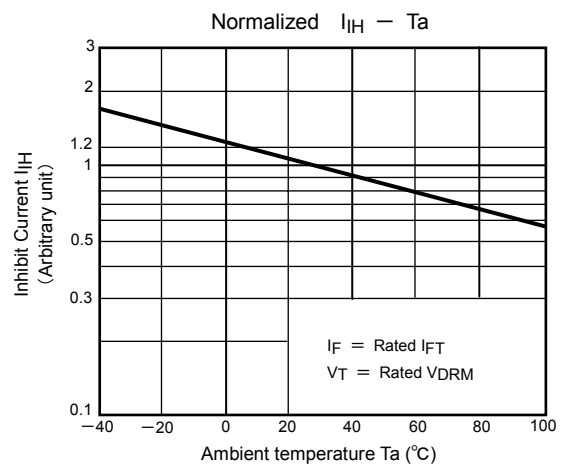
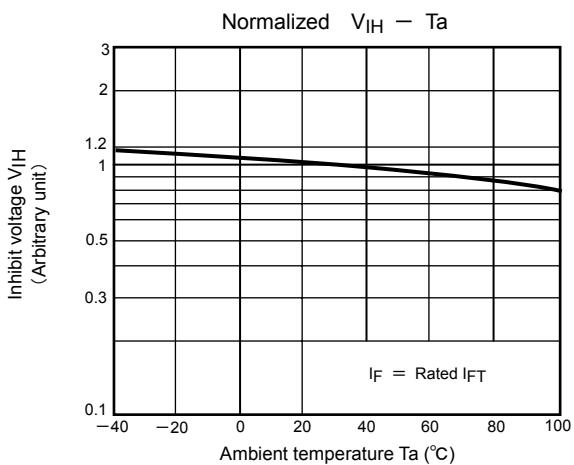
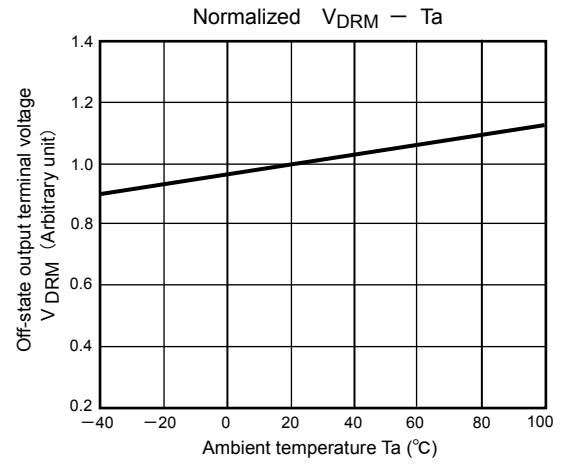
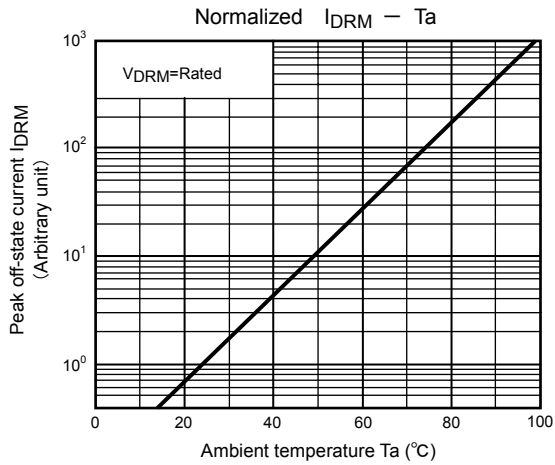
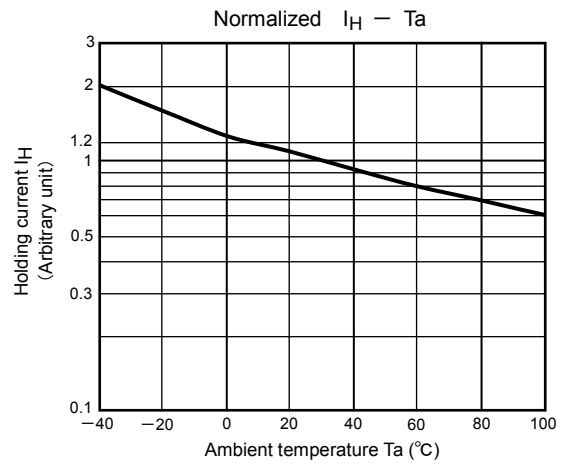
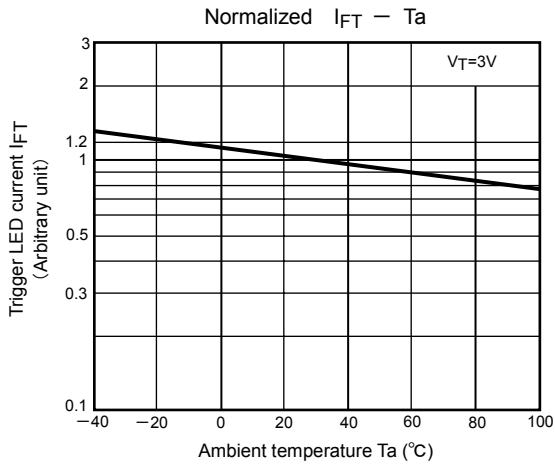
Coupled Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
Trigger LED current	TLP3061(S)	I_{FT}	$V_T = 6 \text{ V}$	—	—	15	mA
	TLP3062(S)			—	5	10	
	TLP3063(S)			—	—	5	
Inhibit voltage	V_{IH}	$I_F = \text{rated } I_{FT}$	—	—	50	V	
Leakage in inhibited state	I_{IH}	$I_F = \text{rated } I_{FT}$ $V_T = \text{rated } V_{DRM}$	—	100	300	μA	
Capacitance input to output	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF	
Isolation resistance	R_S	$V_S = 500 \text{ V (R.H.} \leq 60\%)$	5×10^{10}	10^{14}	—	Ω	
Isolation voltage	BV_S	AC, 1 minute	5000	—	—	Vrms	
		AC, 1 second, in oil	—	10000	—		
		DC, 1 minute, in oil	—	10000	—	V _{dc}	

Fig. 1 dv/dt test circuit







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